



LOW-VOLTAGE 12-BIT 1:2 MUX / DEMUX BUS SWITCH WITH INTERNAL PULL DOWN RESISTORS

IDT74CBTLV16292

FEATURES:

- **5Ω A/B bi-directional switch**
- **Isolation Under Power-Off Conditions**
- **Make-before-break feature**
- **Over-voltage tolerant**
- **Internal 500Ω pull-down resistor to GND**
- **Latch-up performance exceeds 100mA**
- **V_{CC} = 2.3V - 3.6V, normal range**
- **ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)**
- **Available in TSSOP package**

APPLICATIONS:

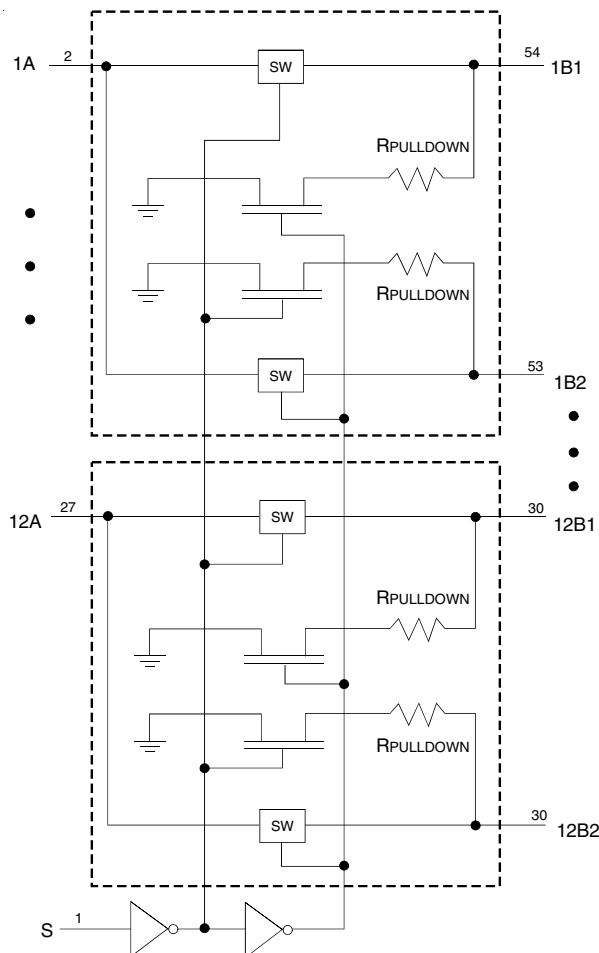
- **3.3V High Speed Bus Switching and Bus Isolation**
- **Resource sharing**

DESCRIPTION:

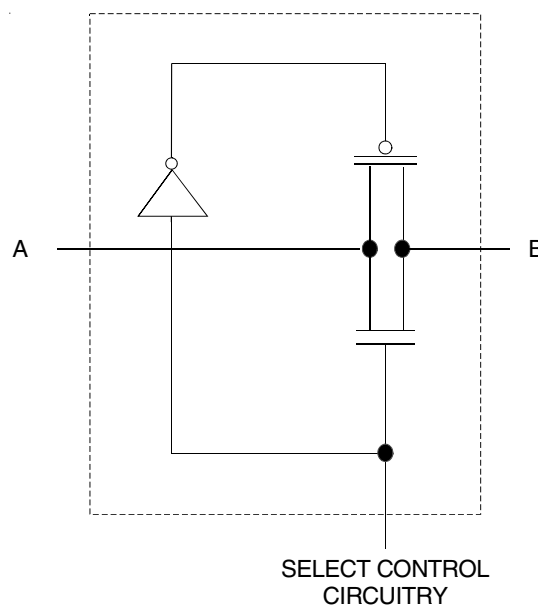
The CBTLV16292 is a single 12-bit multiplexing / demultiplexing bus switch, which provides high speed switching. This device has very low ON resistance, resulting in under 250ps propagation delay through the switch. The demultiplexer side has a 500Ω resistor (R pulldown) termination to GND to eliminate floating nodes.

When the select (S) input is low, the A port is connected to the B1 port, and the R pulldown is connected to the B2 port. Similarly, when the S input is high, A port is connected to B2 port and the R pulldown is connected to B1 port.

FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH

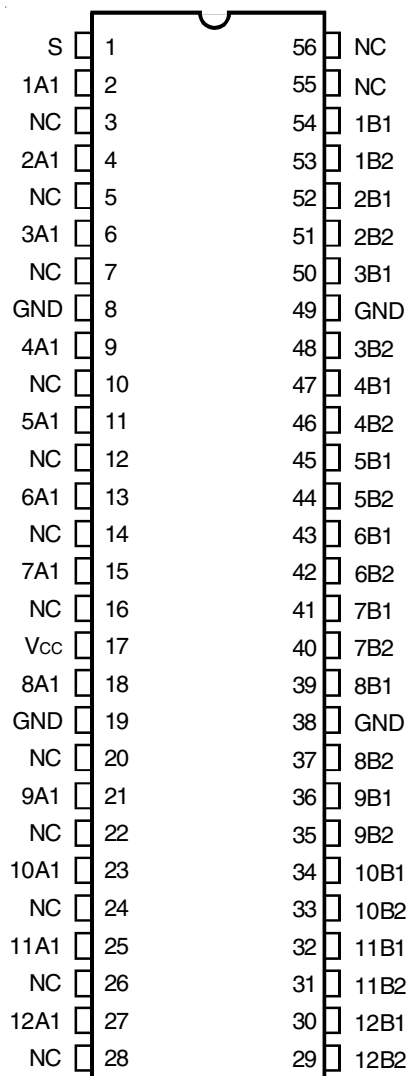


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INDUSTRIAL TEMPERATURE RANGE

JUNE 2006

PIN CONFIGURATION



TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
V _{CC}	Supply Voltage Range	−0.5 to 4.6	V
V _I	Input Voltage Range	−0.5 to 4.6	V
	Continuous Channel Current	128	mA
I _{IK}	Input Clamp Current, V _{I/O} < 0	−50	mA
T _{STG}	Storage Temperature Range	−65 to +150	°C

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

PIN DESCRIPTION

Pin Names	Description
S	Select Input
xAx	Port A Inputs or Outputs
xBx	Port B Inputs or Outputs

FUNCTION TABLE⁽¹⁾

Input	Operation
S	
L	A Port = B1 Port R _{PULLDOWN} = B2 Port
H	A Port = B2 Port R _{PULLDOWN} = B1 Port

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level

OPERATING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V _{CC}	Supply Voltage		2.3	3.6	V
V _{IH}	High-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	1.7	—	V
		V _{CC} = 2.7V to 3.6V	2	—	
V _{IL}	Low-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	—	0.7	V
		V _{CC} = 2.7V to 3.6V	—	0.8	
T _A	Operating Free-Air Temperature		−40	+85	°C

NOTE:

- All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IK}	Control Inputs, Data I/O	V _{CC} = 3V, I _I = −18mA		—	—	−1.2	V
I _I	Control Inputs	V _{CC} = 3.6V, V _I = V _{CC} or GND		—	—	±1	μA
I _{OFF}		V _{CC} = 0V, V _I or V _O = 0V or 3.6V		—	—	10	μA
I _{CC}		V _{CC} = 3.6V, I _O = 0, V _I = V _{CC} or GND		—	—	10	μA
ΔI _{CC} ⁽²⁾	Control Inputs	V _{CC} = 3.6V, one input at 3V, other inputs at V _{CC} or GND		—	—	300	μA
C _I	Control Inputs	V _I = 3.3V or 0		—	3.5	—	pF
C _{IO(OFF)}	A port or B port	V _O = 3.3V or 0		—	22.5	—	pF
R _{ON} ⁽³⁾	Max. at V _{CC} = 2.3V Typ. at V _{CC} = 2.5V	V _I = 0	I _O = 64mA	—	5	8	Ω
			I _O = 24mA	—	5	8	
		V _I = 1.7V	I _O = 15mA	—	11	40	
	V _{CC} = 3V	V _I = 0	I _O = 64mA	—	3	7	
			I _O = 24mA	—	3	7	
		V _I = 2.4V	I _O = 15mA	—	7	15	

NOTES:

1. Typical values are at 3.3V, +25°C ambient.
2. The increase in supply current is attributable to each input that is at the specified voltage level rather than V_{CC} or GND.
3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

Symbol	Parameter	V _{CC} = 2.5V ± 0.2V		V _{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
t _{PD} ⁽¹⁾	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t _{PD} ⁽²⁾	Propagation Delay S to A	2.5	7.1	2.5	6.7	ns
t _{EN}	Output Enable Time S to B	1	5.6	1	5	ns
t _{DIS}	Output Disable Time S to B	1	5	1	4.5	ns
t _{MB/B} ^(3,4)	Make-Before-Break Time	0	2	0	2	ns

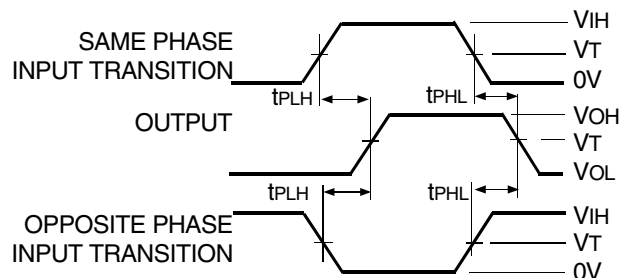
NOTES:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
2. The condition to measure this propagation delay is by observing the change of voltage on the A port introduced by static fields equal to 3V or 0V for 3.3V±0.3V or V_{CC} or 0 for 2.5V±0.2V on B₁ and B₂ ports to get the required transition.
3. The make-before-break time is the duration between the make and break, during transition from one selected port to another.
4. This parameter is guaranteed by design but not production tested.

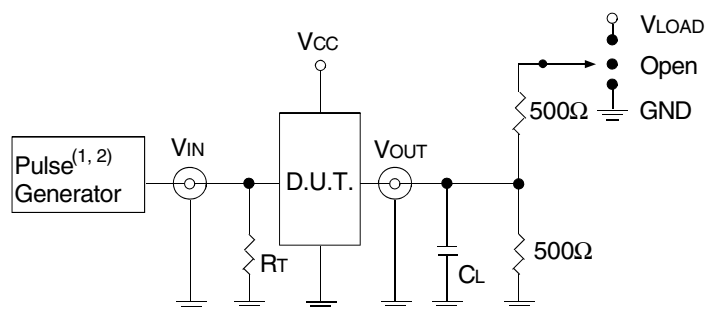
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	$2 \times V_{CC}$	V
V_{IH}	3	V_{CC}	V
V_T	1.5	$V_{CC} / 2$	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF



Propagation Delay



Test Circuits for All Outputs

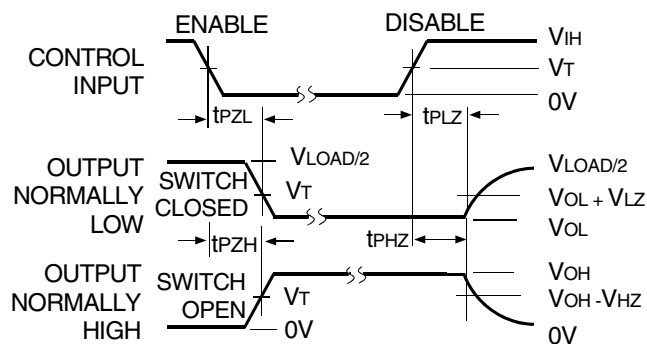
DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_r \leq 2.5\text{ns}$; $t_f \leq 2.5\text{ns}$.
2. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_r \leq 2\text{ns}$; $t_f \leq 2\text{ns}$.



NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
2. Disable Low waveform applies to outputs that are LOW, except when disabled by the output control S.

Enable and Disable Times

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ORDERING INFORMATION

IDT	XX	CBTLV	XXX	XX	
Temp. Range		Device Type		Package	
				PA PAG	Thin Shrink Small Outline Package TSSOP - Green
				16292	Low-Voltage 12-Bit Mux / Demux Bus Switch with Internal Pull Down Resistors
				74	−40°C to +85°C



CORPORATE HEADQUARTERS
 6024 Silver Creek Valley Road
 San Jose, CA 95138

for SALES:
 800-345-7015 or 408-284-8200
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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9